

OPA404

Quad High-Speed Precision Difet® OPERATIONAL AMPLIFIER

FEATURES

- WIDE BANDWIDTH: 6.4MHz
- HIGH SLEW RATE: 35V/µs
- LOW OFFSET: ±750µV max
- LOW BIAS CURRENT: ±4pA max
- LOW SETTLING: 1.5µs to 0.01%
- STANDARD QUAD PINOUT

DESCRIPTION

The OPA404 is a high performance monolithic *Difet*[®](dielectrically-isolated FET) quad operational amplifier. It offers an unusual combination of very-low bias current together with wide bandwidth and fast slew rate.

Noise, bias current, voltage offset, drift, and speed are superior to BIFET[®] amplifiers.

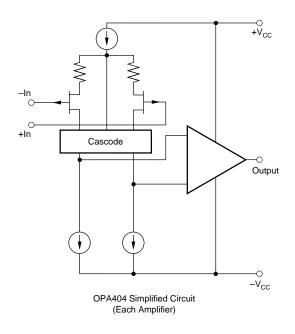
Laser-trimming of thin-film resistors gives very low offset and drift—the best available in a quad FET op amp.

The OPA404's input cascode design allows high precision input specifications and uncompromised highspeed performance.

Standard quad op amp pin configuration allows upgrading of existing designs to higher performance levels. The OPA404 is unity-gain stable.

APPLICATIONS

- PRECISION INSTRUMENTATION
- OPTOELECTRONICS
- SONAR, ULTRASOUND
- PROFESSIONAL AUDIO EQUIPMENT
- MEDICAL EQUIPMENT
- DETECTOR ARRAYS



Difet[®], Burr-Brown Corp. BIFET[®], National Semiconductor Corp.

International Airport Industrial Park • Mailing Address: PO Box 11400 • Tucson, AZ 85734 • Street Address: 6730 S. Tucson Blvd. • Tucson, AZ 85706 Tel: (520) 746-1111 • Twx: 910-952-1111 • Cable: BBRCORP • Telex: 066-6491 • FAX: (520) 889-1510 • Immediate Product Info: (800) 548-6132

© 1986 Burr-Brown Corporation

Printed in U.S.A. August 1995

SPECIFICATIONS

ELECTRICAL

At V_{CC} = $\pm 15 VDC$ and T_A = +25°C unless otherwise noted.

		OPA4	04AG, KP,	KU ⁽¹⁾	(OPA404B	G		OPA404SO	G	
PARAMETER	CONDITIONS	MIN	TYP	MAX	MIN	ТҮР	МАХ	MIN	ТҮР	MAX	UNITS
INPUT											
NOISE											
Voltage: f _O = 10Hz			32			*			*		nV/√Hz
f _O = 100Hz			19			*			*		nV/√ <u>Hz</u>
$f_0 = 1 kHz$			15			*			*		nV/√Hz
$f_0 = 10 \text{kHz}$			12			*			*		nV/√Hz
$f_B = 10Hz$ to $10kHz$			1.4			*			^		μVrms
$f_B = 0.1Hz$ to 10Hz			0.95 12			*			*		μVp-p
Current: $f_B = 0.1Hz$ to 10Hz $f_O = 0.1Hz$ thru 20kHz			0.6			*			*		fA, p-p fA/√Hz
°											
OFFSET VOLTAGE Input Offset Voltage	V _{CM} = 0VDC		±260	±1mV		*	±750		*	*	μV
KP, KU	*CM = 0*80		±200 ±750	±2.5mV			100				μν μV
Average Drift	$T_A = T_{MIN}$ to T_{MAX}		±3			*			*		μV/°C
KP, KU			±5								μV/°C
Supply Rejection	$\pm V_{CC}$ = 12V to 18V	80	100		86	*		*	*		dB
KP, KU		76	100								dB
Channel Separation	100Hz, $R_L = 2k\Omega$		125			*			*		dB
BIAS CURRENT											
Input Bias Current	$V_{CM} = 0VDC$		±1	±8		*	±4		*	*	pА
KP, KU			±1	±12							pА
OFFSET CURRENT											
Input Offset Current	$V_{CM} = 0VDC$		0.5	8		*	4		*	*	pА
KP, KU			0.5	12							pА
IMPEDANCE											
Differential			10 ¹³ 1			*			*		Ω pF
Common-Mode			1014 3			*			*		Ω pF
VOTAGE RANGE											
Common-Mode Input Range		±10.5	+13, –11		*	*		*	*		V
Common-Mode Rejection	$V_{IN} = \pm 10 VDC$	88	100		92	*		*	*		dB
KP, KU		84	100								dB
OPEN-LOOP GAIN, DC											
Open-Loop Voltage Gain	$R_L \ge 2k\Omega$	88	100		92	*		*	*		dB
FREQUENCY RESPONSE											
Gain Bandwidth	Gain = 100	4	6.4		5	*		*	*		MHz
Full Power Response	20Vp-p, $R_L = 2k\Omega$		570			*			*		kHz
	$V_0 = \pm 10V, R_L = 2k\Omega$	24	35		28	*		*	*		V/μs
Settling Time: 0.1%	Gain = -1 , R _L = $2k\Omega$		0.6 1.5			*			*		μs
	C _L = 100 pF, 10V Step		1.5								μs
	D alko	+14 5	12.2 42	0	*	*		*	*		
Voltage Output	$R_L = 2k\Omega$ $V_\Omega = \pm 10VDC$	±11.5 + ±5	-13.2, –13. ±10	0	*	*		*	*		V mA
Current Output Output Resistance	$v_0 = \pm 10$ VDC 1MHz, Open Loop	<u></u> 3	±10 80			*			*		mA Ω
Load Capacitance Stability	Gain = $+1$		1000			*			*		pF
Short Circuit Current		±10	±27	±40	*	*	*	*	*	*	mA
POWER SUPPLY											
Rated Voltage			±15			*			*		VDC
Voltage Range,											
Derated Performance		±5		±18	*		*	*		*	VDC
Current, Quiescent	I _O = 0mADC		9	10		*	*		*	*	mA
TEMPERATURE RANGE											
Specification	Ambient Temperature	-25		+85	*		*	-55		+125	°C
KP, KU		0		+70							°C
	Ambient Temperature	-55		+125	*		*	*		*	°C
KP, KU	l=	-25		+85							°C
Storage	Ambient Temperature	-65		+150	*		*	*		*	°C
5											
KP, KU θ Junction-Ambient		-40	100	+125		•			↓		°C °C/W

*Specifications same as OPA404AG.

NOTE: (1) OPA404KU may be marked OPA404U.

The information provided herein is believed to be reliable; however, BURR-BROWN assumes no responsibility for inaccuracies or omissions. BURR-BROWN assumes no responsibility for the use of this information, and all use of such information shall be entirely at the user's own risk. Prices and specifications are subject to change without notice. No patent rights or licenses to any of the circuits described herein are implied or granted to any third party. BURR-BROWN does not authorize or warrant any BURR-BROWN product for use in life support devices and/or systems.



ELECTRICAL (FULL TEMPERATURE RANGE SPECIFICATIONS)

At V_{CC} = $\pm 15 VDC$ and T_A = T_{MIN} to T_{MAX} unless otherwise noted.

		OPA	404AG, K	P, KU		OPA404B	G		OPA404SO	3	
PARAMETER	CONDITIONS	MIN	ТҮР	MAX	MIN	TYP	МАХ	MIN	ТҮР	МАХ	UNITS
TEMPERATURE RANGE Specification Range KP, KU	Ambient Temperature	-25 0		+85 +70	*		*	-55		+125	°C °C
INPUT OFFSET VOLTAGE Input Offset Voltage KP KU Average Drift KP, KU	V _{CM} = 0VDC		±450 ±1 ±3 ±5	2mV ±3.5		*	±1.5mV		±550 *	±2.5mV	μV mV μV/°C μV/°C
Supply Rejection		75	96		80	*		70	93		dB
BIAS CURRENT Input Bias Current	V _{CM} = 0VDC		±32	±200		*	±100		±500	±5nA	pА
OFFSET CURRENT Input Offset Current	V _{CM} = 0VDC		17	100		*	50		260	2.5nA	pА
VOLTAGE RANGE Common-Mode Input Range Common-Mode Rejection KP, KU	V _{IN} = ±10VDC	±10 82 80	±12.7, –10 99 99	.6	* 86	*		±10 + 80	+12.6, –10. 88	5	V dB dB
OPEN-LOOP GAIN, DC Open-Loop Voltage Gain	$R_L \ge 2k\Omega$	82	94		86	*		80	88		dB
RATED OUTPUT Voltage Output Current Output Short Circuit Current	$R_{L} = 2k\Omega$ $V_{O} = \pm 10VDC$ $V_{O} = 0VDC$	±11.5 ± ±5 ±8	±12.9, –13 ±9 ±20	.8 ±50	* *	* * *	*	±11 + * *	+12.7, –13. ±8 *	8	V mA mA
POWER SUPPLY Current, Quiescent	I _O = 0mADC		9.3	10.5		*	*		9.4	11	mA

* Specification same as OPA404AG.

ORDERING INFORMATION

MODEL	PACKAGE	TEMPERATURE RANGE
MODEL	TACKAGE	KANGL
OPA404KP	14-Pin Plastic DIP	0°C to +70°C
OPA404KU ⁽¹⁾	16-Pin Plastic SOIC	0°C to +70°C
OPA404AG	14-Pin Ceramic DIP	–25°C to +85°C
OPA404BG	14-Pin Ceramic DIP	–25°C to +85°C
OPA404SG	14-Pin Ceramic DIP	-55°C to +125°C

NOTE: (1) OPA404KU may be marked OPA404U.

ABSOLUTE MAXIMUM RATINGS

PACKAGE INFORMATION

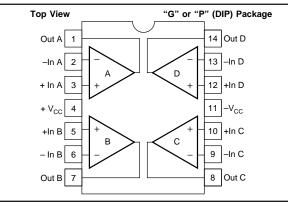
MODEL	PACKAGE	PACKAGE DRAWING NUMBER ⁽¹⁾
OPA404KP OPA404KU ⁽²⁾ OPA404AG OPA404BG	14-Pin Plastic DIP 16-Pin Plastic SOIC 14-Pin Ceramic DIP 14-Pin Ceramic DIP	010 211 169 169
OPA404SG	14-Pin Ceramic DIP	169

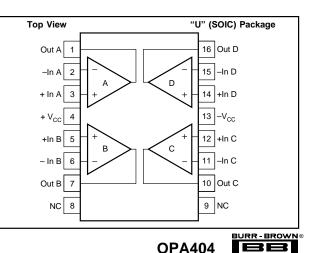
NOTE: (1) For detailed drawing and dimension table, please see end of data sheet, or Appendix D of Burr-Brown IC Data Book. (2) OPA404KU may be marked OPA404U.

Operating Temperature Range P, U = -25°C/+85°C	C, G = −55°C/+125°C
Lead Temperature (soldering, 10s)	300°C
SOIC (soldering, 3s)	+260°C
Output Short-Circuit Duration ⁽³⁾	Continuous
Junction Temperature	+175°C

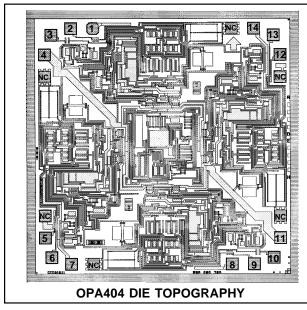
NOTES: (1) Packages must be derated based on $\theta_{JC} = 30^{\circ}$ C/W or $\theta_{JA} = 120^{\circ}$ C/W. (2) For supply voltages less than ±18VDC the absolute maximum input voltage is equal to: 18V > $V_{IN} > -V_{CC} - 8V$. See Figure 2. (3) Short circuit may be to power supply common only. Rating applies to +25°C ambient. Observe dissipation limit and T_J.

PIN CONFIGURATION





DICE INFORMATION



PAD	FUNCTION	PAD	FUNCTION
1	Output A	8	Output C
2	-Input A	9	–Input C
3	+Input A	10	+Input C
4	+V _{CC}	11	-V _{cc}
5	+Input B	12	+Input D
6	-Input B	13	–Input D
7	Output B	14	Output D

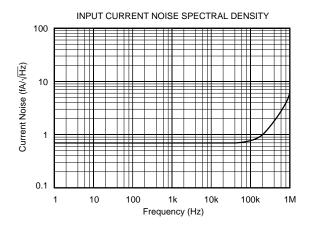
Substrate Bias: -V_{CC} NC: No connection

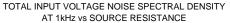
MECHANICAL INFORMATION

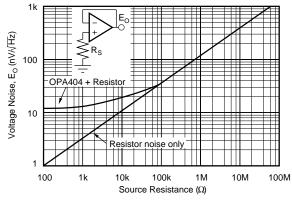
	MILS (0.001")	MILLIMETERS
Die Size	108 x 108 ±5	2.74 x 2.74 ±0.13
Die Thickness	20 ±3	0.51 ±0.08
Min. Pad Size	4 x 4	0.10 x 0.10
Backing		None

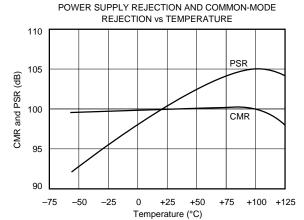
TYPICAL PERFORMANCE CURVES

 $T_A = +25^{\circ}C$, $V_{CC} = \pm 15VDC$ unless otherwise noted.

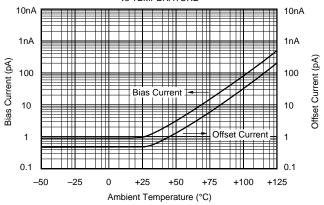








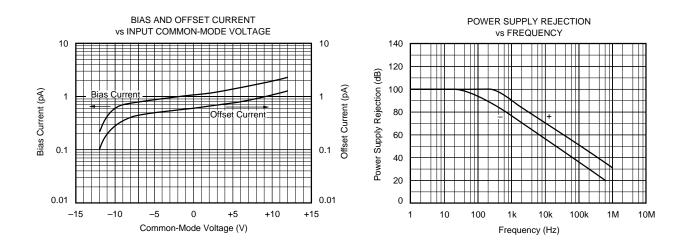
BIAS AND OFFSET CURRENT vs TEMPERATURE

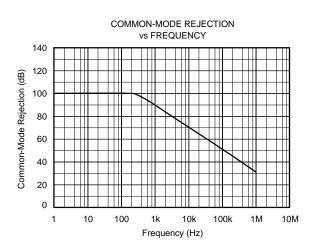


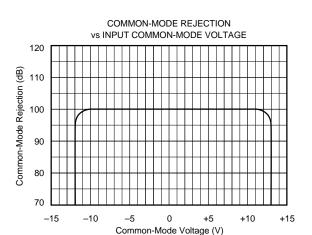


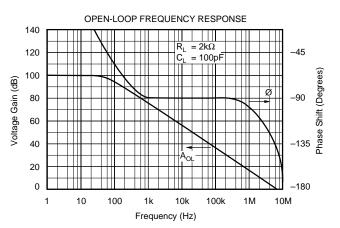
TYPICAL PERFORMANCE CURVES (CONT)

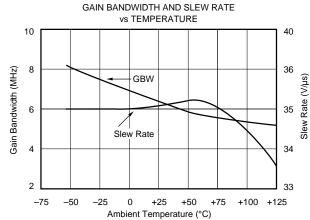
 T_{A} = +25°C, V_{CC} = ±15VDC unless otherwise noted.







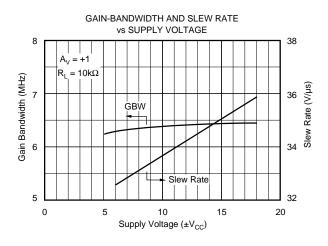


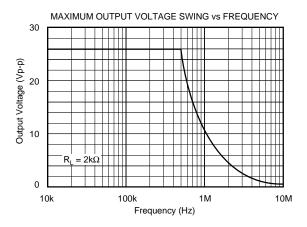


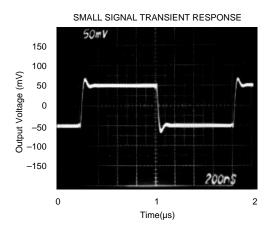


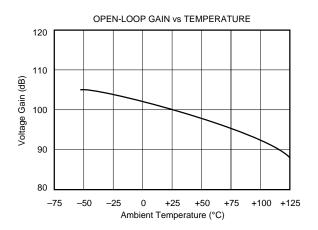
TYPICAL PERFORMANCE CURVES (CONT)

 T_{A} = +25°C, V_{CC} = ±15VDC unless otherwise noted.

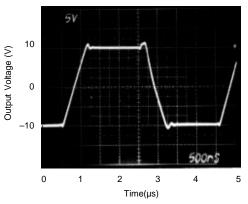


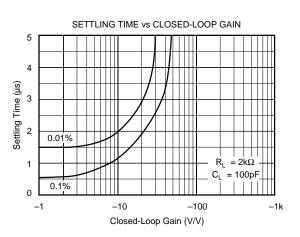






LARGE SIGNAL TRANSIENT RESPONSE

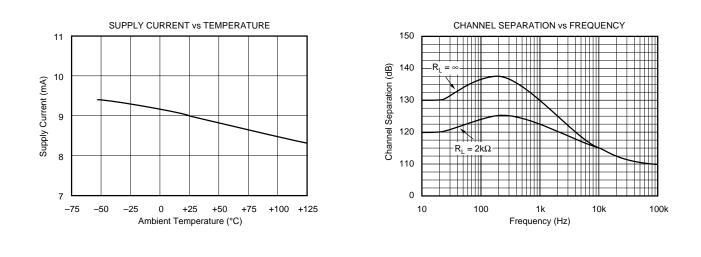


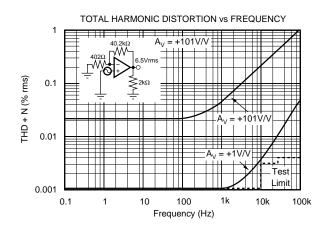


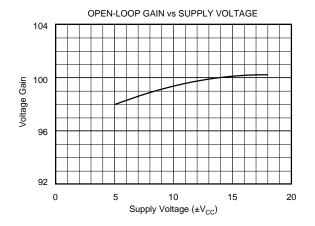


TYPICAL PERFORMANCE CURVES (CONT)

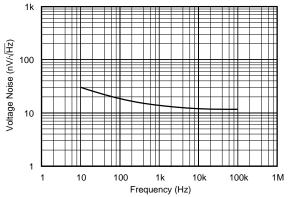
 T_{A} = +25°C, V_{CC} = $\pm 15 VDC$ unless otherwise noted.













APPLICATIONS INFORMATION

OFFSET VOLTAGE ADJUSTMENT

The OPA404 offset voltage is laser-trimmed and will require no further trim for most applications. If desired, offset voltage can be trimmed by summing (see Figure 1). With this trim method there will be no degradation of input offset drift.

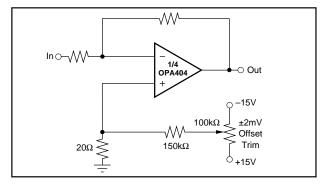


FIGURE 1. Offset Voltage Trim.

INPUT PROTECTION

Conventional monolithic FET operational amplifiers require external current-limiting resistors to protect their inputs against destructive currents that can flow when input FET gate-to-substrate isolation diodes are forward-biased. Most BIFET amplifiers can be destroyed by the loss of $-V_{CC}$.

Unlike BIFET amplifiers, the **Difet** OPA404 requires input current limiting resistors only if its input voltage is greater than 8 volts more negative than $-V_{CC}$. A 10k Ω series resistor will limit the input current to a safe value with up to ±15V input levels even if both supply voltages are lost. (See Figure 2 and Absolute Maximum Ratings).

Static damage can cause subtle changes in amplifier input characteristics without necessarily destroying the device. In precision operational amplifiers (both bipolar and FET types), this may cause a noticeable degradation of offset voltage and drift.

Static protection is recommended when handling any precision IC operational amplifier.

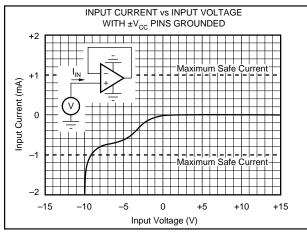


FIGURE 2. Input Current vs Input Voltage with ±V_{CC} Pins Grounded.

GUARDING AND SHIELDING

As in any situation where high impedances are involved, careful shielding is required to reduce "hum" pickup in input leads. If large feedback resistors are used, they should also be shielded along with the external input circuitry.

Leakage currents across printed circuit boards can easily exceed the bias current of the OPA404. To avoid leakage, utmost care must be used in planning the board layout. A "guard" pattern should completely surround the high impedance input leads and should be connected to a low-impedance point which is at the signal input potential. (See Figure 3).

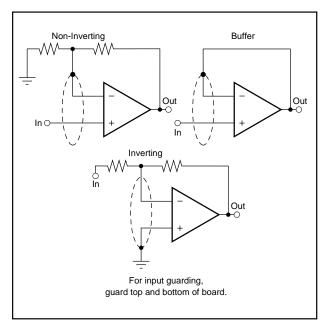


FIGURE 3. Connection of Input Guard.

HANDLING AND TESTING

Measuring the unusually low bias current of the OPA404 is difficult without specialized test equipment; most commercial benchtop testers cannot accurately measure the OPA404 bias current. Low-leakage test sockets and special test fixtures are recommended if incoming inspection of bias current is to be performed.

To prevent surface leakage between pins, the DIP package should not be handled by bare fingers. Oils and salts from fingerprints or careless handling can create leakage currents that exceed the specified OPA404 bias currents.

If necessary, DIP packages and PC board assemblies can be cleaned with Freon TF[®], baked for 30 minutes at 85°C, rinsed with de-ionized water, and baked again for 30 minutes at 85°C. Surface contamination can be prevented by the application of a high-quality conformal coating to the cleaned PC board assembly.



BIAS CURRENT CHANGE vs COMMON-MODE VOLTAGE

The input bias currents of most popular BIFET operational amplifiers are affected by common-mode voltage (Figure 4). Higher input FET gate-to-drain voltage causes leakage and ionization (bias) currents to increase. Due to its cascode input stage, the extremely low bias current of the OPA404 is not compromised by common-mode voltage.

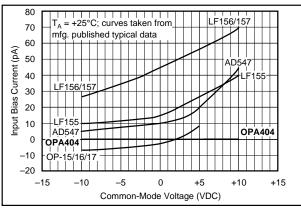


FIGURE 4. Input Bias Current vs Common-Mode Voltage.

APPLICATIONS CIRCUITS

Figures 5 through 11 are circuit diagrams of various applications for the OPA404.

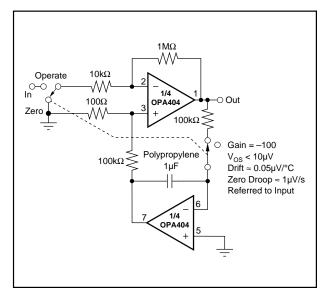


FIGURE 5. Auto-Zero Amplifier.

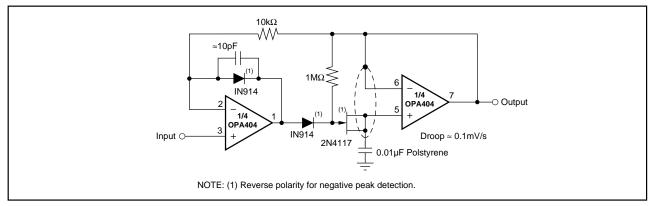


FIGURE 6. Low-Droop Positive Peak Detector.



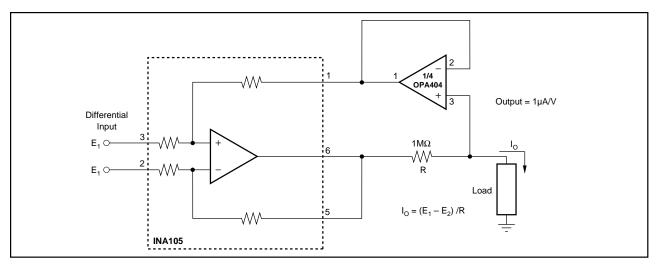


FIGURE 7. Voltage-Controlled Microamp Current Source.

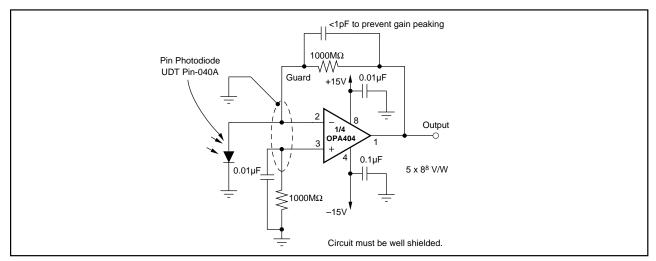


FIGURE 8. Sensitive Photodiode Amplifier.

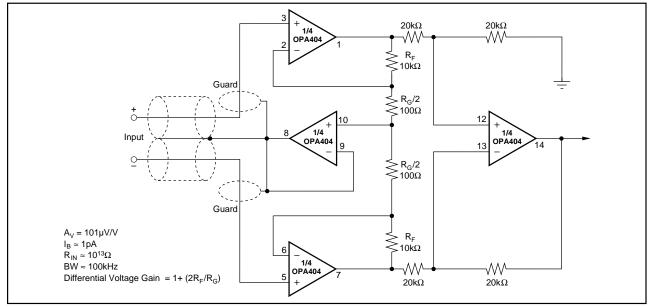


FIGURE 9. FET Instrumentation Amplifier with Shield Driver.



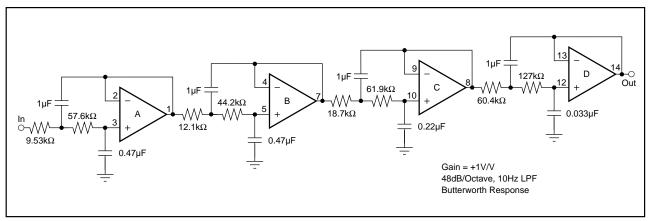
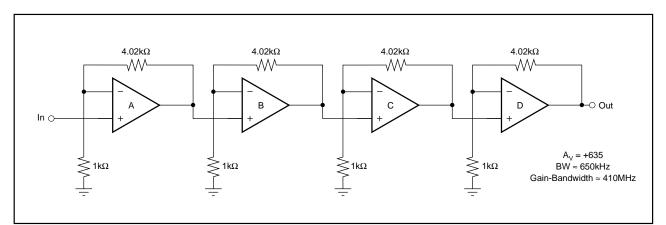


FIGURE 10. 8-Pole 10Hz Low-Pass Filter.



11

FIGURE 11. Wide-Band Amplifier.





10-Jun-2014

PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	•	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
OPA404AG	NRND	CDIP SB	JD	14	1	Green (RoHS & no Sb/Br)	AU	N / A for Pkg Type		OPA404AG	
OPA404BG	NRND	CDIP SB	JD	14	1	Green (RoHS & no Sb/Br)	AU	N / A for Pkg Type		OPA404BG	
OPA404KP	ACTIVE	PDIP	Ν	14	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type		OPA404KP	Samples
OPA404KPG4	ACTIVE	PDIP	Ν	14	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type		OPA404KP	Samples
OPA404KU	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	0 to 70	OPA404KU	Samples
OPA404KU/1K	ACTIVE	SOIC	DW	16	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	0 to 70	OPA404KU	Samples
OPA404KUG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	0 to 70	OPA404KU	Samples
OPA404SG	NRND	CDIP SB	JD	14	1	Green (RoHS & no Sb/Br)	AU	N / A for Pkg Type		OPA404SG	

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



www.ti.com

10-Jun-2014

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com

Texas Instruments

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal	

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	()	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OPA404KU/1K	SOIC	DW	16	1000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1

TEXAS INSTRUMENTS

www.ti.com

PACKAGE MATERIALS INFORMATION

26-Jan-2013



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OPA404KU/1K	SOIC	DW	16	1000	367.0	367.0	38.0

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products		Applications	
Audio	www.ti.com/audio	Automotive and Transportation	www.ti.com/automotive
Amplifiers	amplifier.ti.com	Communications and Telecom	www.ti.com/communications
Data Converters	dataconverter.ti.com	Computers and Peripherals	www.ti.com/computers
DLP® Products	www.dlp.com	Consumer Electronics	www.ti.com/consumer-apps
DSP	dsp.ti.com	Energy and Lighting	www.ti.com/energy
Clocks and Timers	www.ti.com/clocks	Industrial	www.ti.com/industrial
Interface	interface.ti.com	Medical	www.ti.com/medical
Logic	logic.ti.com	Security	www.ti.com/security
Power Mgmt	power.ti.com	Space, Avionics and Defense	www.ti.com/space-avionics-defense
Microcontrollers	microcontroller.ti.com	Video and Imaging	www.ti.com/video
RFID	www.ti-rfid.com		
OMAP Applications Processors	www.ti.com/omap	TI E2E Community	e2e.ti.com
Wireless Connectivity	www.ti.com/wirelessconne	ectivity	

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2014, Texas Instruments Incorporated

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Texas Instruments:

OPA404KPG4 OPA404KUG4 OPA404AG OPA404BG OPA404KP OPA404KU OPA404KU/1K OPA404SG